## SPDT SWITCH GaAs MMIC

## ■ GENERAL DESCRIPTION

The NJG1815K75 is a 1 bit control SPDT switch. The switch is used for WLAN system.
The switch features low insertion loss, high isolation for high frequency up to 6 GHz , and high handling power performance at 1.8 V control voltage. Integrated ESD protection device on each port achieves excellent ESD robustness.
Integrated DC blocking capacitors at all RF ports and the ultra small package of DFN6-75 offer very small mounting area.

PACKAGE OUTLINE


NJG1815K75

## APPLICATION

$802.11 \mathrm{a} / \mathrm{b} / \mathrm{g} / \mathrm{n} / \mathrm{ac} / \mathrm{ax}$ networks applications
Transmit/receive switching, antenna switching and others switching applications
Smart phone, WLAN module, data card and others mobile applications

## FEATURES

- Low control voltage
- Voltage operation
- Low insertion loss
- High isolation
- P-1dB
- Ultra small \& ultra thin package
- RoHS compliant and Halogen Free, MSL1


## PIN CONFIGURATION

(Top view)


Pin connection

1. P1
2. GND
3. P2
4. VCTL
5. PC
6. VDD

## ■ TRUTH TABLE

$" \mathrm{H} "=\mathrm{V}_{\text {стL }}(\mathrm{H})$, " $\mathrm{L} "=\mathrm{V}_{\text {стL }}(\mathrm{L})$

| ON PATH | VCTL |
| :---: | :---: |
| PC-P1 | H |
| PC-P2 | L |

NOTE: Please note that any data or drawing in this catalog is subject to change.

## ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | CONDITIONS | RATINGS | UNITS |
| :--- | :---: | :---: | :---: | :---: |
| RF Input Power | $\mathrm{P}_{\mathrm{IN}}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}, \mathrm{C}, \mathrm{Z}_{\mathrm{s}}=\mathrm{Z}_{\mathrm{l}}=50 \Omega$ <br> ON State Port |  |  |
| Supply Voltage | $\mathrm{V}_{\mathrm{DD}}$ |  | +31 | dBm |
| Control Voltage | $\mathrm{V}_{\mathrm{CTL}}$ |  | 6.0 | V |
| Power Dissipation | $\mathrm{P}_{\mathrm{D}}$ | 4-layer FR4 PCB with through-hole <br> $(76.2 \times 114.3 \mathrm{~mm}), \mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$ | 380 | mW |
| Operating Temperature | $\mathrm{T}_{\text {opr }}$ |  | 6.0 | V |
| Storage Temperature | $\mathrm{T}_{\text {stg }}$ |  | -40 to +105 | ${ }^{\circ} \mathrm{C}$ |

■ ELECTRICAL CHARACTERISTICS1 (DC CHARACTERISTICS)
(General conditions: $\mathrm{T}_{\mathrm{a}}=+25^{\circ} \mathrm{C}$, with application circuit)

| PARAMETERS | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage | $\mathrm{V}_{\mathrm{DD}}$ |  | 2.5 | 3.3 | 5.0 | V |
| Operating Current | $\mathrm{I}_{\mathrm{DD}}$ | No RF input, $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ | - | 15 | 30 | $\mu \mathrm{~A}$ |
| Control Voltage (HIGH) | $\mathrm{V}_{\text {CTL }}(\mathrm{H})$ |  | 1.35 | 1.8 | 5.0 | V |
| Control Voltage (LOW) | $\mathrm{V}_{\text {CTL }}(\mathrm{L})$ |  | 0 | - | 0.45 | V |
| Control Current | $\mathrm{I}_{\text {CTL }}$ | $\mathrm{V}_{\text {CTL }}(\mathrm{H})=1.8 \mathrm{~V}$ | - | 3 | 10 | $\mu \mathrm{~A}$ |

■ ELECTRICAL CHARACTERISTICS2 (RF CHARACTERISTICS)
(General conditions: $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {CTL }}(\mathrm{H})=1.8 \mathrm{~V}, \mathrm{~V}_{\text {CTL }}(\mathrm{L})=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{a}}=+25^{\circ} \mathrm{C}, \mathrm{Z}_{\mathrm{S}}=\mathrm{Z}_{\mathrm{l}}=50 \Omega$, with application circuit)

| PARAMETERS | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| Insertion loss1 | LOSS1 | $\mathrm{f}=2.4$ to 2.5 GHz | - | 0.45 | 0.65 | dB |
| Insertion loss2 | LOSS2 | $\mathrm{f}=3.4$ to 3.8 GHz | - | 0.45 | 0.65 | dB |
| Insertion loss3 | LOSS3 | $\mathrm{f}=4.9$ to 6.0 GHz | - | 0.40 | 0.60 | dB |
| Isolation1 | ISL1 | $\mathrm{f}=2.4$ to 2.5 GHz | 23 | 25 | - | dB |
| Isolation2 | ISL2 | $\mathrm{f}=3.4$ to 3.8 GHz | 22 | 25 | - | dB |
| Isolation3 | ISL3 | $\mathrm{f}=4.9$ to 6.0 GHz | 22 | 25 | - | dB |
| Return loss1 | RL1 | $\mathrm{f}=2.4$ to 2.5 GHz | 13 | 16 | - | dB |
| Return loss2 | RL2 | $\mathrm{f}=3.4$ to 3.8 GHz | 15 | 20 | - | dB |
| Return loss3 | RL3 | $\mathrm{f}=4.9$ to 6.0 GHz | 15 | 20 | - | dB |
| Input power at 1dB <br> compression point | P-1dB | $\mathrm{f}=2.4$ to 6.0 GHz | +28 | +31 | - | dBm |
| Switching time | T SW | $50 \% \mathrm{~V}_{\mathrm{ctL}}$ to $10 \% / 90 \% \mathrm{RF}$ | - | 150 | 400 | ns |

TERMINAL INFORMATION

| No. | SYMBOL | DESCRIPTION |
| :---: | :---: | :--- |
| 1 | P1 | RF terminal. No DC blocking capacitor is required for this port because of <br> internal capacitor. |
| 2 | GND | Ground terminal. Please connect this terminal with ground plane as close as <br> possible for excellent RF performance. |
| 3 | P2 | RF terminal. No DC blocking capacitor is required for this port because of <br> internal capacitor. |
| 4 | VCTL | Control voltage input terminal. This terminal is set to High-Level (+1.35 to <br> $+5.0 V)$ or Low-Level (0 to $+0.45 \mathrm{~V})$. |
| 5 | PC | Common RF terminal. No DC blocking capacitor is required for this port <br> because of internal capacitor. |
| 6 | VDD | Positive voltage supply terminal. The positive voltage (+2.5 to +5.0V) has to <br> be supplied. Please connect a bypass capacitor with GND terminal for <br> excellent RF performance. |

## ELECTRICAL CHARACTERISTICS



Return Loss vs Frequency
(PC-P1 ON, $\left.\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{CTL}}=1.8 \mathrm{~V}\right)$


Switching Time
(PC-P1 path, $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{cTL}(\mathrm{H})}=1.8 \mathrm{~V}$ )


Time (100ns/div)


Return Loss vs Frequency


## ELECTRICAL CHARACTERISTICS



Loss, ISL vs Input Power
( $\mathrm{PC}-\mathrm{P} 1 \mathrm{ON}, \mathrm{V}_{\mathrm{cTL}}=1.8 \mathrm{~V}, \mathrm{f}=2.5 \mathrm{GHz}$ )




Loss, ISL vs Input Power
( $\mathrm{PC}-\mathrm{P} 2 \mathrm{ON}, \mathrm{V}_{\mathrm{ctL}}=0 \mathrm{~V}, \mathrm{f}=2.5 \mathrm{GHz}$ )


## ELECTRICAL CHARACTERISTICS

Loss, ISL vs Input Power
(PC-P1 ON, $\mathrm{V}_{\mathrm{crL}}=1.8 \mathrm{~V}, \mathrm{f}=6.0 \mathrm{GHz}$ )


EVM vs Input Power
(PC-P1 ON, $\mathrm{V}_{\mathrm{CrL}}=1.8 \mathrm{~V}, \mathrm{f}=2.5 \mathrm{GHz}$, OFDM 64QAM)


EVM vs Input Power
(PC-P1 ON, $\mathrm{V}_{\mathrm{cTL}}=1.8 \mathrm{~V}, \mathrm{f}=6.0 \mathrm{GHz}$, OFDM 64QAM)


Loss, ISL vs Input Power
(PC-P2 ON, $\mathrm{V}_{\mathrm{ctL}}=0 \mathrm{~V}, \mathrm{f}=6.0 \mathrm{GHz}$ )


EVM vs Input Power
(PC-P2 ON, $\mathrm{V}_{\mathrm{CTL}}=0 \mathrm{~V}, \mathrm{f}=2.5 \mathrm{GHz}$, OFDM 64QAM)


EVM vs Input Power
(PC-P2 ON, $V_{\text {cTL }}=0 V, f=6.0 \mathrm{GHz}$, OFDM 64QAM)


## ELECTRICAL CHARACTERISTICS

Loss, ISL vs Temperature
(PC-P1 ON, $\mathrm{V}_{\mathrm{cTL}}=1.8 \mathrm{~V}, \mathrm{f}=2.5 \mathrm{GHz}$ )


Loss, ISL vs Temperature
(PC-P1 ON, $\mathrm{V}_{\mathrm{cTL}}=1.8 \mathrm{~V}, \mathrm{f}=6.0 \mathrm{GHz}$ )



Loss, ISL vs Temperature


Loss, ISL vs Temperature
( $\mathrm{PC}-\mathrm{P} 2 \mathrm{ON}, \mathrm{V}_{\mathrm{ctL}}=0 \mathrm{~V}, \mathrm{f}=6.0 \mathrm{GHz}$ )



## ELECTRICAL CHARACTERISTICS




APPLICATION CIRCUIT


The bypass capacitor C2 is optional, and is recommended only when the control line is affected under noisy environment.

## ■ PCB LAYOUT

(TOP VIEW)


PCB: FR-4, $t=0.2 \mathrm{~mm}$
Capacitor Size: 0603 ( $0.6 \times 0.3 \mathrm{~mm}$ )
Strip Line Width: 0.4 mm
PCB Size: $19.4 \times 14.0 \mathrm{~mm}$
Through Hole Diameter: 0.2 mm

- Loss of PCB and connectors

| Frequency $(\mathrm{GHz})$ | Loss $(\mathrm{dB})$ |
| :---: | :---: |
| 2.4 | 0.28 |
| 2.5 | 0.28 |
| 3.4 | 0.35 |
| 3.8 | 0.39 |
| 4.9 | 0.52 |
| 6.0 | 0.72 |

## ■ PARTS LIST

| No. | Value | Notes |
| :---: | :---: | :---: |
| C1 | 1000 pF | Murata MFG <br> (GRM03 series) |
| C2 | 10 pF |  |

## PCB LAYOUT GUIDELINE

(TOP VIEW)


Diameter $\phi=0.2 \mathrm{~mm}$

## PRECAUTIONS

For good RF performance, exposed pad should be connected to PCB ground plane as close as possible.

RECOMMENDED FOOTPRINT PATTERN (6pin DFN Package 1.0x1.0mm) <Reference>

Package: $1.0 \mathrm{~mm} \times 1.0 \mathrm{~mm}$
Pin pitch: 0.35 mm

Z : Land
: Mask (Open area) *Metal mask thickness: $100 \mu \mathrm{~m}$ : Resist (Open area)

Unit : mm


PACKAGE OUTLINE (DFN6-75)


| Unit | $: \mathrm{mm}$ |
| :--- | :--- |
| Board | $: \mathrm{Cu}$ |
| Terminal Treat | $: \mathrm{Ni} / \mathrm{Pd} / \mathrm{Au}$ |
| Molding Material | $:$ Epoxy resin |
| Weight | $: 1.2 \mathrm{mg}$ |

## Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

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[^0]:    This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

